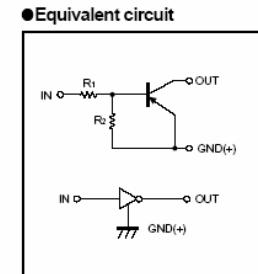
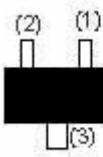
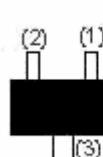
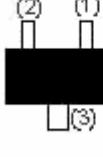
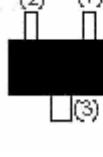
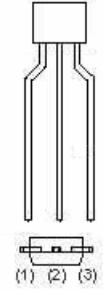


## Features

- 1) Built-in bias resistors enable the configuration of an inverter circuit without connecting external input resistors (see equivalent circuit).
- 2) The bias resistors consist of thin-film resistors with complete isolation to allow negative biasing of the input. They also have the advantage of almost completely eliminating parasitic effects.
- 3) Only the on/off conditions need to be set for operation, making device design easy.



## PIN CONNECTIONS AND MARKING

<p><b>DTA143XE</b></p>  <p>1.IN 2.GND 3.OUT</p> <p>SOT-523      Addreviated symbol: 33</p>	<p><b>DTA143XUA</b></p>  <p>1.IN 2.GND 3.OUT</p> <p>SOT-323      Addreviated symbol: 33</p>
<p><b>DTA143XKA</b></p>  <p>1.IN 2.GND 3.OUT</p> <p>SOT-23-3L      Addreviated symbol: 33</p>	<p><b>DTA143XCA</b></p>  <p>1.IN 2.GND 3.OUT</p> <p>SOT-23      Addreviated symbol: 33</p>
<p><b>DTA143XSA</b></p>  <p>1.GND 2.OUT 3.IN</p> <p>TO-92S</p>	

**Absolute maximum ratings (Ta=25°C)**

Parameter	Symbol	Limits (DTA143X )					Unit
		E	UA	CA	KA	SA	
<b>Supply voltage</b>	V <sub>CC</sub>	-50					V
<b>Input voltage</b>	V <sub>IN</sub>	-20~+7					V
<b>Output current</b>	I <sub>O</sub>	-100					mA
	I <sub>C(MAX)</sub>	-100					
<b>Power dissipation</b>	P <sub>d</sub>	150		200		300	mW
<b>Junction temperature</b>	T <sub>j</sub>	150					°C
<b>Storage temperature</b>	T <sub>stg</sub>	-55~150					°C

**Electrical characteristics (Ta=25°C)**

Parameter	Symbol	Min.	Typ	Max.	Unit	Conditions
<b>Input voltage</b>	V <sub>I(off)</sub>			-0.3	V	V <sub>CC</sub> =-5V, I <sub>O</sub> =-100μA
	V <sub>I(on)</sub>	-2.5				V <sub>O</sub> =-0.3V, I <sub>O</sub> =-20 mA
<b>Output voltage</b>	V <sub>O(on)</sub>		-0.1	-0.3	V	I <sub>O</sub> /I <sub>I</sub> =-10mA/-0.5mA
<b>Input current</b>	I <sub>I</sub>			-1.8	mA	V <sub>I</sub> =-5V
<b>Output current</b>	I <sub>O(off)</sub>			-0.5	μA	V <sub>CC</sub> =-50V, V <sub>I</sub> =0
<b>DC current gain</b>	G <sub>I</sub>	30				V <sub>O</sub> =-5V, I <sub>O</sub> =-10mA
<b>Input resistance</b>	R <sub>I</sub>	3.29	4.7	6.11	KΩ	
<b>Resistance ratio</b>	R <sub>2</sub> /R <sub>1</sub>	1.7	2.1	2.6		
<b>Transition frequency</b>	f <sub>T</sub>		250		MHz	V <sub>O</sub> =-10V, I <sub>O</sub> =5mA, f=100MHz

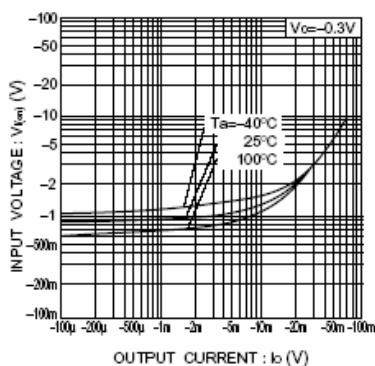
**Typical Characteristics**


Fig.1 Input voltage vs. output current (ON characteristics)

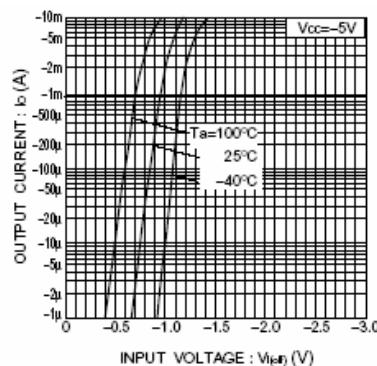


Fig.2 Output current vs. input voltage (OFF characteristics)

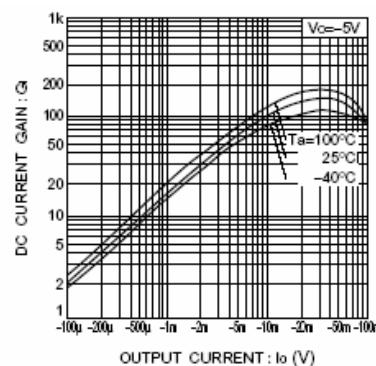


Fig.3 DC current gain vs. output current

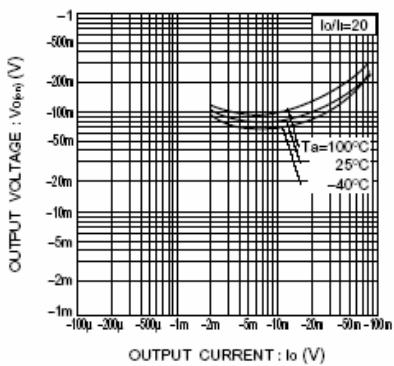


Fig.4 Output voltage vs. output current